

R	leg	g. No:]			
SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR																
(AUTONOMOUS) B.Tech I Year I Semester Supplementary Examinations July-2022																
ADVANCED PHYSICS																
T		2.1				(M	lechar	nical I	Engine	ering)					60
T	me	: 3 hours			(•	,	U	T T •/	F 1		0.14	1 \		Max	x. Marl	ks: 60
					(Ans	wer a	ll Five		5 X I) T T	2 = 6	0 Mar	KS)				
1	a	Write brie	ef note	on ex	perim	ental a	arrang	ement	of Ne	wton'	s ring	s.		L	.1	7M
	b	Explain l Newton's	how t ring.	he wa	ivelen	gth o	f ligh	t sou	rces i	s dete	ermine	ed by	formir	ng L	.2	5M
								Ol	R							
2	a	Derive the positions	ne con due to	dition single	s to slit d	get pr ue to]	rincipa Fraunl	al maz hofer s	kimun single	and and slit dif	mini: fracti	mum on.	intensit	ty L	.4	7M
	b	• Draw intensity distribution curves and give condition for bright and dark fringes in single slit diffraction pattern.									rk L	.1	5M			
								UNI	Г-Н							
3	a	Write Sal	bine's peratio	formu n time	ıla foi	reve	rberati	ion tir	ne? M	ention	n fact	ors co	ntrollin	ng L	.1	7M
	b	A hall of If the are absorption	volum ea of n coeff	the softent	0 m ³ i ound ?	s foun absort	nd to h bing s	ave a surface	revert e is 3	eratio 50 m	on time 2 , cale	e of 2 culate	second averag	s. L ge	.3	5M
		1						O	R							
4	a	How ultra	asonics	are p	roduce	ed by	using	piezoe	electric	gene	rator?		3	3 –	2	8M
	b A quartz crystal has a thickness of Calculate its fundamental frequency $8.2 \times 10^{10} \text{ N/m}^2$.							of 4 x 10 ⁻⁵ and density 3 x 10 ⁵ kg/m ⁵ . y. Give the Youngs modulus of crystal is						is L	3	4M
_								UNIT	'-III		_					
5	a	Describe moments	the c	lassific	cation	of m	agnet	ic ma	terials	base	d on	spin 1	magneti	ic L	.1	8M
	b	Discuss th	ne app	licatio	ns of s	soft m	agneti	c mate	erials. R					L	.2	4M
6	a	Explain expression	pheno n for t	menor	n of	electr	ic po	larizat	tion i	n die	lectric	cs. D	erive a	in L	.2	8M
	b	The diele polarizabi	ctric control of the second se	onstan He at	t of H oms if	e gas a f the g	at NTI as con	P is 1.9 Itains 2 UNIT	00006 2.7 x 1 2 -IV	84. ca 0 ²⁵ at	lculate oms p	e the e ber m ³ .	electron	ic L	.3	4M
7	a	Explain the energy level	he con vel dia	structi gram.	ion an	d wor	king j	princij	ole of	He-N	e lase	r with	suitab	le L	.2	8M
	b	Write few	v advar	itages	of He	-Ne la	ser.	_	_					L	.1	4M
8	a	What is th	ne acco	eptanc	e angl	e of a	n optio	Ol cal fib	∢ re?ar	id deri	ve an	expre	ssion fo	or L	1	8M
	b	it. An optical index of 1	al fibro 1.40. F	e has ind its	a core θ_a .	e refra	ctive	index	of 1.4	4 and	l clad	ding r	efractiv	ve L	.3	4 M

Q	. P .	R19		
		UNIT-V		
9	a	Explain why surface to volume ratio very large for nano materials.	L2	7M
	b	Write the applications of Nano materials.	L1	5M
		OR		
10	a	How we synthesis nanomaterial by Sol-Gel technique.	L2	8M
	b	Write advantages of sol-gel process.	L1	4M

*** END ***